

Pb Free Plating Product

HERA1601G thru HERA1608G



16.0 Ampere Glass Passivated Process High Efficiency Rectifiers

Features

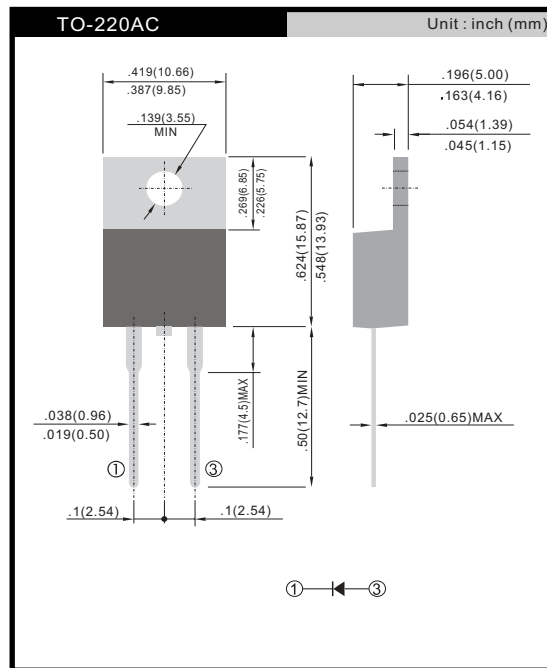
- * Glass passivated chip junction
- * Low forward voltage drop
- * High current capability
- * Low reverse leakage current
- * High surge current capability

Application

- * Automotive Inverters/Solar Inverters
- * Plating Power Supply, SMPS and UPS
- * Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- * Case: Heatsink TO-220AC
- * Epoxy: UL 94V-0 rate flame retardant
- * Terminals: Solderable per MIL-STD-202 method 208
- * Polarity: As marked on diode body
- * Mounting position: Any
- * Weight: 2.1 gram approxiamtely



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	HERA 1601G	HERA 1602G	HERA 1603G	HERA 1604G	HERA 1605G	HERA 1606G	HERA 1607G	HERA 1608G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	16								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	250								A
Maximum Instantaneous Forward Voltage (Note 1) @ 16 A	V_F	1.0			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25\text{ }^\circ\text{C}$	I_R	10								μA
at Rated DC Blocking Voltage @ $T_A=125\text{ }^\circ\text{C}$		400								μA
Maximum Reverse Recovery Time (Note 2)	T_{rr}	50				80				nS
Typical Junction Capacitance (Note 3)	C_j	120				80				pF
Typical Thermal Resistance	$R_{\theta JC}$	2.0								$^\circ\text{C/W}$
Operating Temperature Range	T_J	- 65 to + 150								$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 65 to + 150								$^\circ\text{C}$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle
 Note 2: Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $IRR=0.25\text{A}$
 Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (HERA1601G thru HERA1608G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

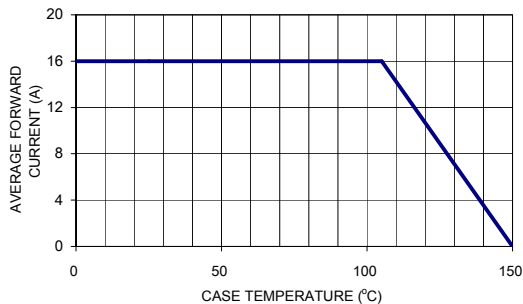


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

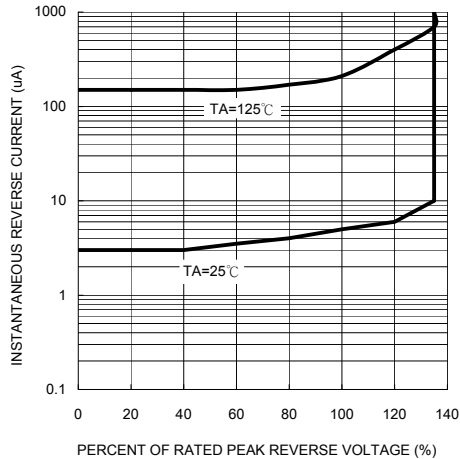


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

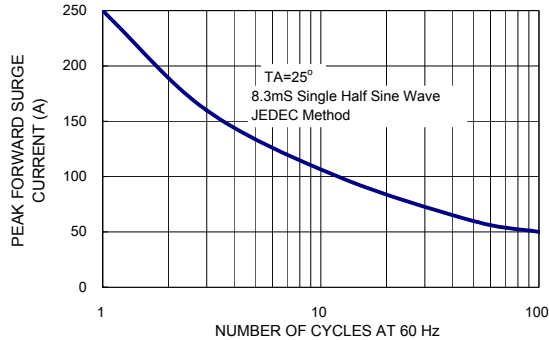


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

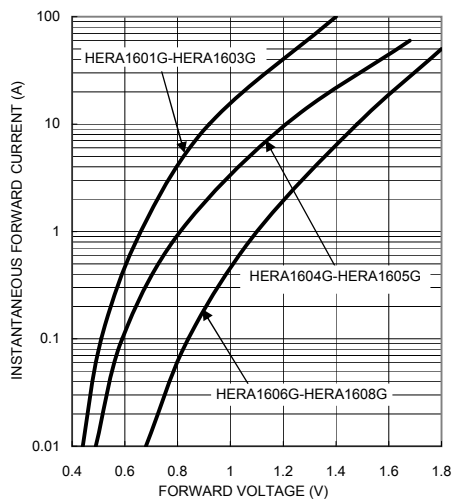


FIG. 4- TYPICAL JUNCTION CAPACITANCE

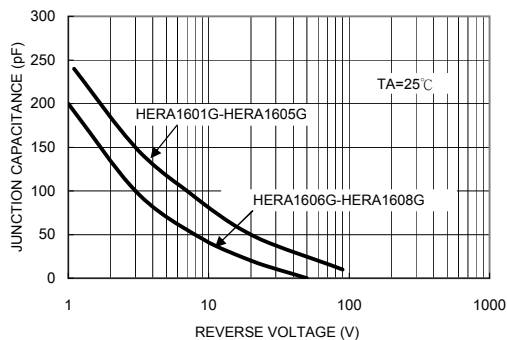


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

